# imall

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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







#### **Features**

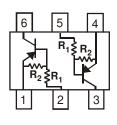
- Epitaxial Planar Die Construction
- Complementary NPN Types Available (DDC)
- **Built-In Biasing Resistors**
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

P/N	R1 (NOM)	R2 (NOM)	MARKING
DDA122LH	0.22KΩ	10KΩ	P81
DDA142JH	0.47KΩ	10KΩ	P82
DDA122TH	0.22KΩ	OPEN	P83
DDA142TH	0.47KΩ	OPEN	P84

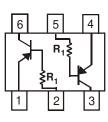
#### **Mechanical Data**

- Case: SOT-563
- Case Material: Molded Plastic; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208@3
- Terminal Connections: See Diagram
- Weight: 0.005 grams (Approximate)

SOT-563 SCHEMATIC DIAGRAM, TOP VIEW



R<sub>1</sub>, R<sub>2</sub>



R1 Only

Note 5

#### Ordering Information (Note 4)

Device	Packaging	Shipping
DDA122LH-7	SOT-563	3,000/Tape & Reel
DDA142JH-7	SOT-563	3,000/Tape & Reel
DDA122TH-7	SOT-563	3,000/Tape & Reel
DDA142TH-7	SOT-563	3,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

- 4. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.
- 5. Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed.

#### Marking Information

SOT-563
PXXYM

XXX = Product Type Marking Code YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Kev

Year	2002	2003	2004	200	5 20	06 20	007	2008	1	2009	2010	2011	2012
Code	Ν	Р	R	S	Т	-	U	V		W	Х	Y	Z
Month	Jan	Feb	Mar	Apr	May	Jun	Ju		ug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7		8	9	0	Ν	D

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#### Maximum Ratings, R1, R2 Types (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Supply Voltage		V <sub>CC</sub>	-50	v
Input Voltage	DDA122LH DDA142JH	VIN	+5 to -6 +5 to -6	V
Input Voltage	DDA122TH DDA142TH	V <sub>EBO (MAX)</sub>	-5	V
Output Current	All	Ic	-100	mA
Power Dissipation		Pd	150	mW
Thermal Resistance, Junction to Ambient Air		$R_{ ext{ heta}JA}$	833	°C/W
Operating and Storage Temperature Range		Tj, T <sub>STG</sub>	-55 to +150	°C

# Electrical Characteristics, R1, R2 Types (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Input Voltage	DDA122LH DDA142JH	V <sub>I(off)</sub>	-0.3 -0.3	_	_	V	V <sub>CC</sub> = -5V, I <sub>O</sub> = -100µA
	DDA122LH DDA142JH	V <sub>I(on)</sub>	_	_	-2.0 -2.0		V <sub>O</sub> = -0.3V, I <sub>O</sub> = -20mA V <sub>O</sub> = -0.3V, I <sub>O</sub> = -20mA
Output Voltage		V <sub>O(on)</sub>		_	-0.3V	V	I <sub>O</sub> /I <sub>I</sub> = -5mA/-0.25mA
Input Current DDA122LH DDA142JH		lı			-28 -13	mA	V <sub>I</sub> = -5V
Output Current		I <sub>O(off)</sub>	_	_	-0.5	μA	$V_{CC} = -50V, V_1 = 0V$
DC Current Gain	DDA122LH DDA142JH	Gı	56 56	_	_	_	V <sub>O</sub> = -5V, I <sub>O</sub> = -10mA
Gain-Bandwidth Product*		f <sub>T</sub>		200	—	MHz	V <sub>CE</sub> = -10V, I <sub>E</sub> = -5mA, f = 100MHz

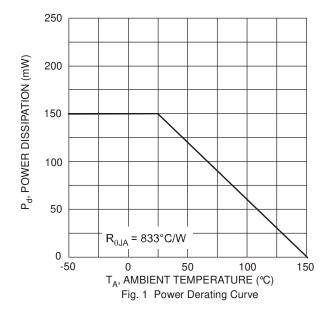
\* Transistor - For Reference Only

## Electrical Characteristics, R1 Only (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Мах	Unit	Test Condition
Collector-Base Breakdown Voltage		BV <sub>CBO</sub>	-50	_		V	I <sub>C</sub> = -50μA
Collector-Emitter Breakdown Voltage		BV <sub>CEO</sub>	-40		_	V	I <sub>C</sub> = -1mA
Emitter-Base Breakdown Voltage DDA122TH DDA142TH		BV <sub>EBO</sub>	-5		_	V	I <sub>E</sub> = -50μA I <sub>E</sub> = -50μA
Collector Cut-Off Current		I <sub>CBO</sub>	—	_	-0.5	μA	V <sub>CB</sub> = -50V
Emitter Cut-Off Current DDA122TH DDA142TH		I <sub>EBO</sub>			-0.5 -0.5	μA	V <sub>EB</sub> = -4V
Collector-Emitter Saturation Voltage		V <sub>CE(sat)</sub>	_		-0.3	V	I <sub>C</sub> = -5mA, I <sub>B</sub> = -0.25mA
DC Current Transfer Ratio	DDA122TH DDA142TH	h <sub>FE</sub>	100 100	250 250	600 600		I <sub>C</sub> = -1mA, V <sub>CE</sub> = -5V
Gain-Bandwidth Product*		f⊤	_	200		MHz	V <sub>CE</sub> = -10V, I <sub>E</sub> = 5mA, f = 100MHz

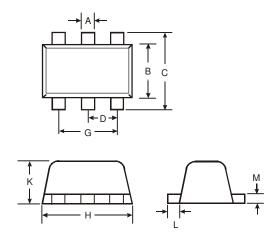
\* Transistor - For Reference Only





#### **Package Outline Dimensions**

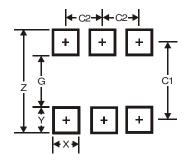
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SOT563								
Dim	Min	Max	Тур						
Α	0.15	0.30	0.20						
В	1.10	1.25	1.20						
С	1.55	1.70	1.60						
D	-	-	0.50						
G	0.90	1.10	1.00						
Η	1.50	1.70	1.60						
Κ	0.55	0.60	0.60						
L	0.10	0.30	0.20						
М	0.10	0.18	0.11						
All	Dimens	sions in	mm						

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)				
Z	2.2				
G	1.2				
Х	0.375				
Y	0.5				
C1	1.7				
C2	0.5				



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